

Flasher, 18-m Ω Shunt

Description

The bipolar integrated circuit, U6043B, is used in relaycontrolled automotive flashers where a high level EMC is required. Lamp outage is indicated by frequency doubling during hazard warning as well as direction mode.

Features

- Temperature and supply voltage compensated flashing frequency
- Frequency doubling indicates lamp outage
- Relay driver output with high current carrying capacity and low saturation voltage
- Minimum lamp load for flasher operation: ≥ 1 W
- Very low susceptibility to EMI
- Protection according to ISO/TR 7637/1 level 4

Ordering Information

Extended Type Number	Package	Remarks
U6043B	DIP8	
U6043B-FP	SO8	

Block Diagram

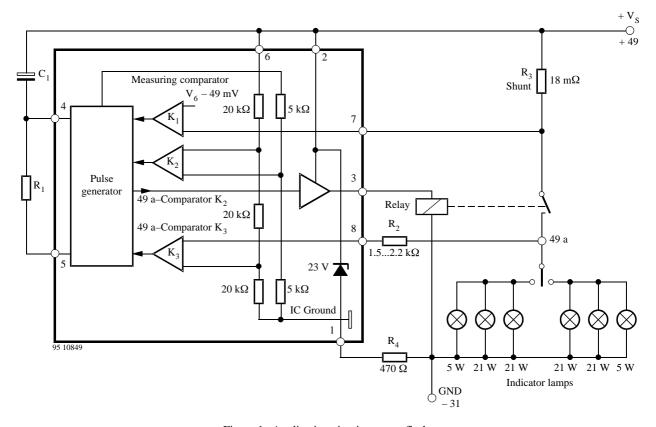


Figure 1. Application circuit as a car flasher



Pin Description

Pin	Symbol	Function
1	GND	IC ground
2	V_{S}	Supply voltage
3	REL	Relay driver
4	OSC	Oscillator
5	OSC	Oscillator
6	V_{S}	Supply voltage, Sense
7	LD	Lamp outage detection
8	SI	Start input (49a)

Functional Description

Pin 1, GND

The integrated circuit is protected against damage via resistor R_4 to ground (-31) in the case of battery reversal. An integrated protection circuit together with external resistances R_2 and R_4 limits the current pulses in the IC.

Pin 2, Supply voltage, V_S - Power

The arrangement of the supply connections to Pin 2 (and 6) must be such as ensure that, on the connection printed circuit board (PCB), the resistance of V_S to Pin 6 is lower than that to Pin 2.

Pin 3, Relay control output (driver)

The relay control output is a high-side driver with a low saturation voltage and capable to drive a typical automotive relay with a minimum coil resistance of 60Ω .

Pin 4 and 5 Oscillator

Flashing frequency, f_1 , is determined by the R_1C_1 components as follows (see figure 1):

$$f_1 \approx \frac{1}{R_1 \times C_1 \times 1.5} \text{ Hz}$$

where

 $C_1 \le 47 \,\mu\text{F}$ $R_1 = 6.8 \,\text{k}\Omega \text{ to } 510 \,\text{k}\Omega$

In the case of a lamp outage (see Pin 7) the oscillator frequency is switched to the lamp outage frequency f_2 with $f_2 \approx 2.2 f_1$.

Duty cycle in normal flashing mode: 50% Duty cycle in lamp outage mode: 40% (bright phase)

Pin 6, Supply voltage, Sense

For accurate monitoring via the shunt resistor, a minimized layer resistance from point $V_S\ /\$ shunt to Pin 6 is recommended.

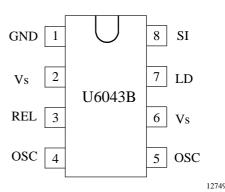


Figure 2. Pinning

Pin 7, Lamp outage detection

The lamp current is monitored via an external shunt resistor R_{sh} and an internal comparator K1 with its reference voltage of typ. 49 mV ($V_S = 12$ V). The outage of one lamp out of two lamps is detected according to the following calculation:

Nominal current of 1 lamp: $21 \text{ W} / (V_S = 12 \text{ V})$:

 $I_{lamp} = 1.75 A$

Nominal current of 2 lamps: $2 \times 21 \text{ W} / (V_S = 12 \text{ V})$:

 $I_{lamp} = 3.5 A.$

The detection threshold is recommended to be set in the middle of the current range: $I_{outage} \approx 2.7 \text{ A}$

Thus the shunt resistor is calculated as:

 $R_{sh} = V_T \left(K1 \right) / \, I_{outage}$

 $R_{sh} = 49 \text{ mV}/2.7 \text{ A} = 18 \text{ m}\Omega.$

Comparator K1's reference voltage is matched to the characteristics of filament lamps (see "control signal threshold" in the data part).

The combination of shunt resistor and resistance of wire harness prevents Pin 7 from a too high voltage in the case of shortet lamps.

Pin 8, Start input

Start condition for flashing: the voltage at Pin 8 has to be below K3 threshold (flasher switch closed).

Humidity and dirt may decrease the resistance between 49 a and GND. If this leakage resistance is $> 5~\mathrm{k}\Omega$ the IC is still kept in its off-condition. In this case the voltage at Pin 8 is between the thresholds of comparators K2 and K3.

During the bright phase the voltage at Pin 8 is above the K2 threshold, during the dark phase it is below the K3 threshold.

For proper start conditions a minimum lamp wattage of 1 W is required.



Absolute Maximum Ratings

Reference point Pin 1

Parameters		Symbol	Value	Unit
Supply voltage	Pins 2 and 6	V_{S}	16,5	V
Surge forward current				
$t_p = 0.1 \text{ ms}$	Pins 2 and 6		1.5	A
$t_p = 300 \text{ ms}$	Pins 2 and 6	I_{FSM}	1.0	A
$t_{\rm p}^{\rm r} = 300 \; {\rm ms}$	Pin 8		50.0	mA
Output current	Pin 3	I _O	0.3	A
Power dissipation				
$T_{amb} = 95^{\circ}C$	DIP8		420	
	SO8	P _{tot}	340	mW
$T_{amb} = 60^{\circ}C$	DIP8		690	
	SO8		560	
Junction temperature		T _j	150	°C
Ambient temperature rang	e	T _{amb}	-40 to + 95	°C
Storage temperature range	,	T _{stg}	-55 to +150	°C

Thermal Resistance

Parameters		Symbol	Value	Unit
Junction ambient	DIP8	R_{thJA}	110	K/W
	SO8	R_{thJA}	160	K/W

Electrical Characteristics

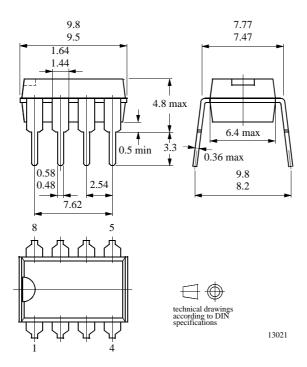
Typical values under normal operation in application circuit (see figure 1), V_S (+49, Pin 2 and 6) = 12 V. Reference point ground (-31), $T_{amb} = 25^{\circ}C$, unless otherwise specified

Parameters	Test conditions / Pin		Symbol	Min.	Тур.	Max.	Unit
Supply voltage range	Pins 2 and 6		V_{S}	9		15	V
Supply current	Dark phase, Pins 2 and 6		I_S		4.5	8	mA
	Bright phase, Pins 2	and 6	I_S		7.0	11	mA
Relay control output	Pi	n 3					
Saturation voltage	$I_O = 150 \text{ mA}, V_S = 9$	V	V_{O}			1.0	V
reverse current			I_{O}			0.1	mA
Start delay (Delay time)	First bright phase		t _{on}			10	ms
Frequency tolerance	Normal flashing		Δf_1	-5		+5	%
Bright period	Basic frequency	f_1	Δf_1	47		53	%
	Control frequency	f_2	Δf_2	37		45	%
Frequency increase	Lamp outage		f_2	$2.15 \times f_1$		$2.3 \times f_1$	Hz
Control signal threshold	$V_S = 15 \text{ V}$	Pin 7		50	53	57	
	$V_S = 9 V$		$V_{(Rs)}$	43	45	47	mV
	$V_S = 12 \text{ V}$			47	49	51	
Leakage resistance	49a to GND		R_{P}		4	5	kΩ
Lamp load			P_{L}	1			W

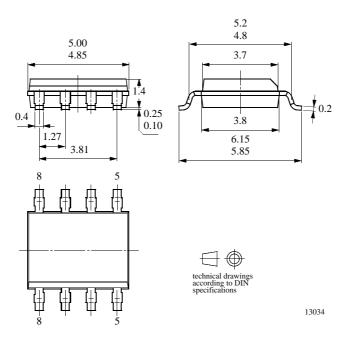


Package Information

Package DIP8
Dimensions in mm



Package SO8 Dimensions in mm





Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

- 1. Meet all present and future national and international statutory requirements.
- Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

TEMIC TELEFUNKEN microelectronic GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423